

BU406, BU407

NPN Power Transistors

These devices are high voltage, high speed transistors for horizontal deflection output stages of TV's and CRT's.

Features

- High Voltage
- Fast Switching Speed
- Low Saturation Voltage
- These Devices are Pb-Free and are RoHS Compliant*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	BU406 BU407 V_{CEO}	200 150	Vdc
Collector-Emitter Voltage	BU406 BU407 V_{CEV}	400 330	Vdc
Collector-Base Voltage	BU406 BU407 V_{CBO}	400 330	Vdc
Emitter-Base Voltage	V_{EBO}	6	Vdc
Collector Current – Continuous – Peak Repetitive	I_C	7 10	Adc
Collector Current – Peak (10 ms)	I_{CM}	15	Adc
Base Current	I_B	4	Adc
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	60 0.48	W W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Storage	T_J, T_{stg}	-65 to 150	$^\circ\text{C}$

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Characteristics	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	2.08	$^\circ\text{C/W}$
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	70	$^\circ\text{C/W}$
Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 5 Seconds	T_L	260	$^\circ\text{C}$

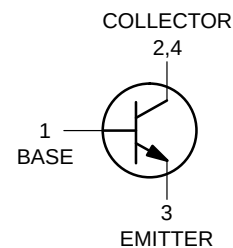


ON Semiconductor®

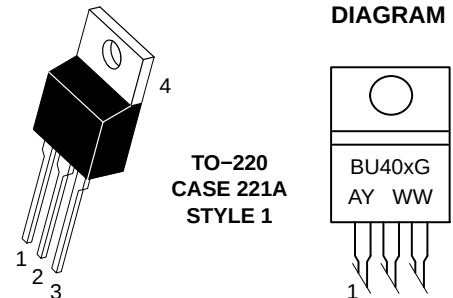
www.onsemi.com

NPN SILICON POWER TRANSISTORS 7 AMPERES – 60 WATTS 150 AND 200 VOLTS

SCHEMATIC



MARKING DIAGRAM



TO-220
CASE 221A
STYLE 1

BU40x = Specific Device Code
x = 6 or 7
A = Assembly Location
Y = Year
WW = Work Week
G = Pb-Free Package

ORDERING INFORMATION

Device	Package	Shipping
BU406G	TO-220AB (Pb-Free)	50 Units / Rail
BU407G	TO-220AB (Pb-Free)	50 Units / Rail

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

BU406, BU407

ELECTRICAL CHARACTERISTICS ($T_C = 25^\circ\text{C}$ unless otherwise noted)

Characteristic		Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS						
Collector-Emitter Sustaining Voltage (Note 1) ($I_C = 100\text{ mAdc}$, $I_B = 0$)	BU406 BU407	$V_{CEO(sus)}$	200 150	– –	– –	Vdc
Collector Cutoff Current ($V_{CE} = \text{Rated } V_{CEV}$, $V_{BE} = 0$) ($V_{CE} = \text{Rated } V_{CEO} + 50\text{ Vdc}$, $V_{BE} = 0$) ($V_{CE} = \text{Rated } V_{CEO} + 50\text{ Vdc}$, $V_{BE} = 0$, $T_C = 150^\circ\text{C}$)		I_{CES}	– – –	– – –	5 0.1 1	mAdc
Emitter Cutoff Current ($V_{EB} = 6\text{ Vdc}$, $I_C = 0$)	BU406, BU407	I_{EBO}	–	–	1	mAdc
ON CHARACTERISTICS (Note 1)						
Collector-Emitter Saturation Voltage ($I_C = 5\text{ Adc}$, $I_B = 0.5\text{ Adc}$)		$V_{CE(sat)}$	–	–	1	Vdc
Base-Emitter Saturation Voltage ($I_C = 5\text{ Adc}$, $I_B = 0.5\text{ Adc}$)		$V_{BE(sat)}$	–	–	1.2	Vdc
Forward Diode Voltage ($I_{EC} = 5\text{ Adc}$) "D" only		V_{EC}	–	–	2	Volts
DYNAMIC CHARACTERISTICS						
Current-Gain – Bandwidth Product ($I_C = 0.5\text{ Adc}$, $V_{CE} = 10\text{ Vdc}$, $f_{test} = 20\text{ MHz}$)		f_T	10	–	–	MHz
Output Capacitance ($V_{CB} = 10\text{ Vdc}$, $I_E = 0$, $f = 1\text{ MHz}$)		C_{ob}	–	80	–	pF
SWITCHING CHARACTERISTICS						
Inductive Load Crossover Time ($V_{CC} = 40\text{ Vdc}$, $I_C = 5\text{ Adc}$, $I_{B1} = I_{B2} = 0.5\text{ Adc}$, $L = 150\text{ }\mu\text{H}$)		t_c	–	–	0.75	μs

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. Pulse Test: Pulse Width $\leq 300\text{ }\mu\text{s}$, Duty Cycle $\leq 1\%$.

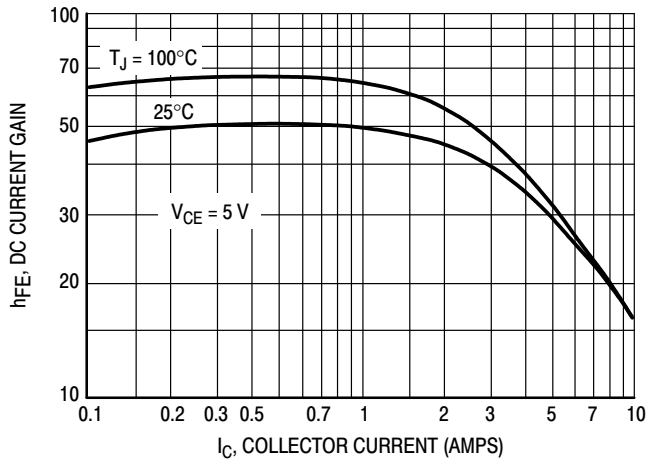


Figure 1. DC Current Gain

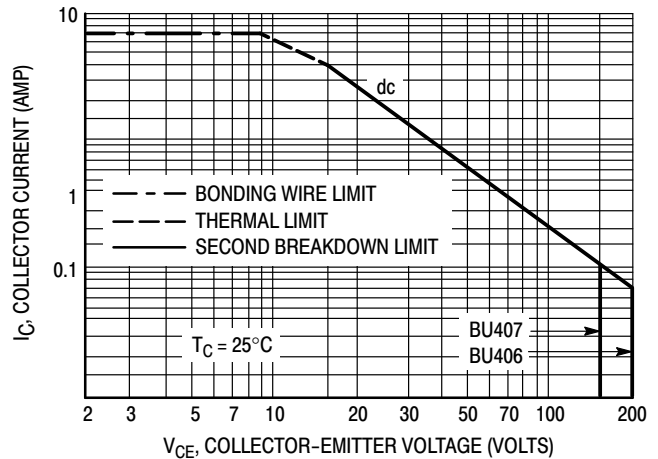


Figure 2. Maximum Rated Forward Bias Safe Operating Area

onsemi, **Onsemi**, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "**onsemi**" or its affiliates and/or subsidiaries in the United States and/or other countries. **onsemi** owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of **onsemi**'s product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. **onsemi** reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and **onsemi** makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

Technical Library: www.onsemi.com/design/resources/technical-documentation
onsemi Website: www.onsemi.com

ONLINE SUPPORT: www.onsemi.com/support

For additional information, please contact your local Sales Representative at
www.onsemi.com/support/sales